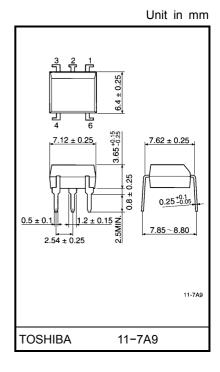
TOSHIBA Photocoupler GaAlAs Ired & Photo-Diode Array

TLP591B

Telecommunication
Programmable Controllers
MOS Gate Driver
MOS FET Gate Driver

The TOSHIBA TLP591B consists of an aluminum galium arsenide infrared emitting diode optically coupled to a series connected photo–diode array in a six lead plastic DIP package. TLP591B is suitable for MOS FET gate driver. TLP591B has an internal shunt resistor to optimize switching speed.

• UL recognized: UL1577, file no. E67349

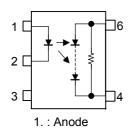


Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit
	Forward current	Ι _Ε	50	mA
	Forward current derating (Ta ≥ 25°C)	ΔI _F /°C	-0.5	mA /°C
LED	Pulse forward current (100µs pulse, 100pps)	I _{FP}	1	Α
	Reverse voltage	V_{R}	3	V
	Junction temperature	Tj	125	°C
or	Forward current	I _{FD}	50	μΑ
Detector	Reverse voltage	V_{RD}	10	V
ă	Junction temperature	Tj	125	°C
Storage temperature range		T _{stg}	-55~125	°C
Operating temperature range		T _{opr}	−40~85	°C
Lead soldering temperature (10 sec.)		T _{sol}	260	°C
	ntion voltage 1 min., R.H.≤ 60%) (Note 1)	BV _S	2500	V _{rms}

(Note 1) Device considered a two terminal device: Pins 1, 2 and 3 shorted together, and pins 4 and 6 shorted together.

Pin Configuration (top view)



2. : Cathode 3. : NC

4. : Cathode 6. : Anode

2002-09-25

Recommended Operating Conditions

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Forward current	I _F	_	20	25	mA
Operating temperature	T _{opr}	-25	_	85	°C

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
	Forward voltage	V_{F}	I _F = 10 mA	1.2	1.4	1.7	V
LED	Reverse current	I _R	V _R = 3 V	_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	60	pF
L	Forward voltage	V_{FD}	I _{FD} = 10 μA	_	7	_	V
Detector	Reverse current	I _{RD}	V _{RD} = 10 V	_	7	_	μΑ
Det	Capacitance (anode to cachode)	C _{TD}	V = 0, f = 1 MHz	_	_		pF

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Open voltage	V _{OC}	I _F = 20 mA	7	8	_	V
Short Current	I _{SC}	I _F = 20 mA	24	40	_	μΑ

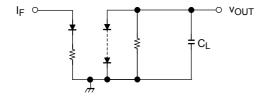
Isolation Characteristics (Ta = 25°C)

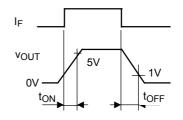
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Capacitance (input to output)	Cs	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V	5×10 ¹⁰	10 ¹⁴	_	
	BVS	AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	_	VIIIIS
		DC, 1 minute, in oil	_	5000	_	Vdc

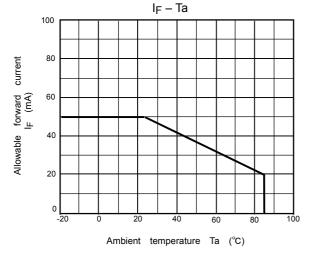
Switching Characteristics (Ta = 25°C)

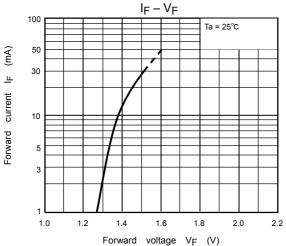
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Turn-on time	t _{on}	I _F = 20 mA, C _L = 1000pF	_	0.2	_	ms
Turn-off time	t _{off}	(Fig. 1)	_	3	-	ms

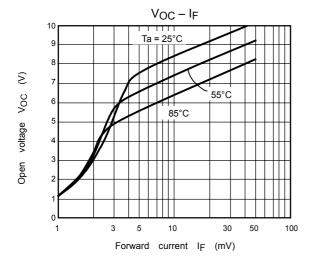
Fig. 1 Switching time test circuit

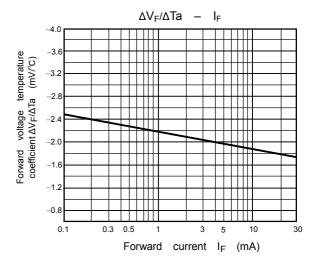


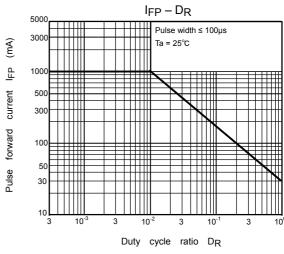


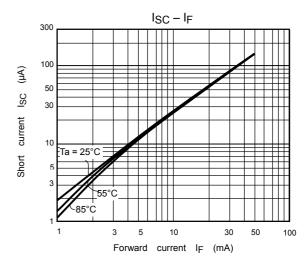












3

RESTRICTIONS ON PRODUCT USE

000707EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes
 are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the
 products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with
 domestic garbage.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.